

Series PVI-N & PbF

Photovoltaic Isolator
Single and Dual Channel
5-10 Volt Output

General Description

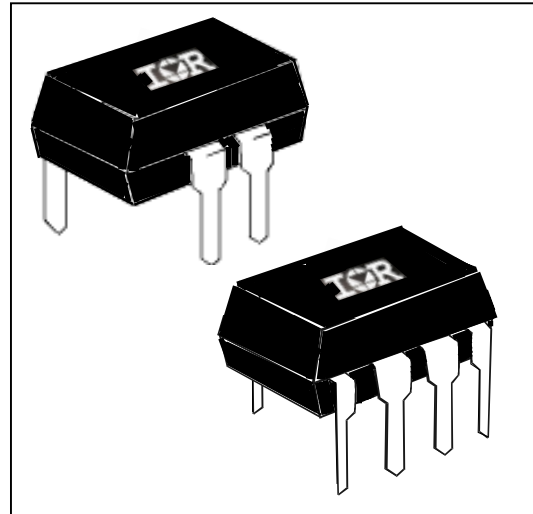
The PVI Series Photovoltaic Isolator generates an electrically isolated DC voltage upon receipt of a DC input signal. It is capable of directly driving gates of power MOSFETs or IGBTs. It utilizes a monolithic integrated circuit photovoltaic generator of novel construction as its output. The output is controlled by radiation from a GaAlAs light emitting diode (LED), which is optically isolated from the photovoltaic generator.

The PVI Series is ideally suited for applications requiring high-current and/or high-voltage switching with optical isolation between the low-level driving circuitry and high-energy or high-voltage load circuits. It can be used for directly driving gates of power MOSFETs. The dual-channel device allows its outputs to drive independent discrete power MOSFETs, or be connected in parallel or in series to provide higher current drive for power MOSFETs or higher voltage drive for IGBTs. The PVI Series Photovoltaic isolators employ fast turn-off circuitry.

These PVI Series Photovoltaic Isolators are packaged in 8-pin, molded DIP packages and available with either thru-hole or surface-mount ("gull-wing") leads, in plastic shipping tubes.

Features

- Isolated Voltage Source
- Monolithic Construction
- Up to 8 μ A Output
- Single or Dual Output
- Solid-State Reliability



Applications

- Load Distribution
- Industrial Controls
- Current-to-Voltage Conversion
- Custom Solid-State Relay

Part Identification

PVI1050N & PbF	thru-hole
PVI5050N & PbF	
PVI5080N & PbF	
PVI1050NS & PbF	surface-mount (gull-wing)
PVI5050NS & PbF	
PVI5080NS & PbF	

Electrical Specifications ($-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ unless otherwise specified)

INPUT CHARACTERISTICS	PVI Series	Units
Input Current Range (see figure 4)	2.0 to 50	mA (DC)
Maximum Forward Voltage Drop @ 10mA, 25°C (see figure 5)	1.4	V (DC)
Maximum Reverse Voltage	6.0	V(DC)
Maximum Reverse Current @ -6.0V (DC), 25°C	100	μA(DC)
Maximum Pulsed Input Current @ 25°C (see figure 6)	1.0	A(peak)

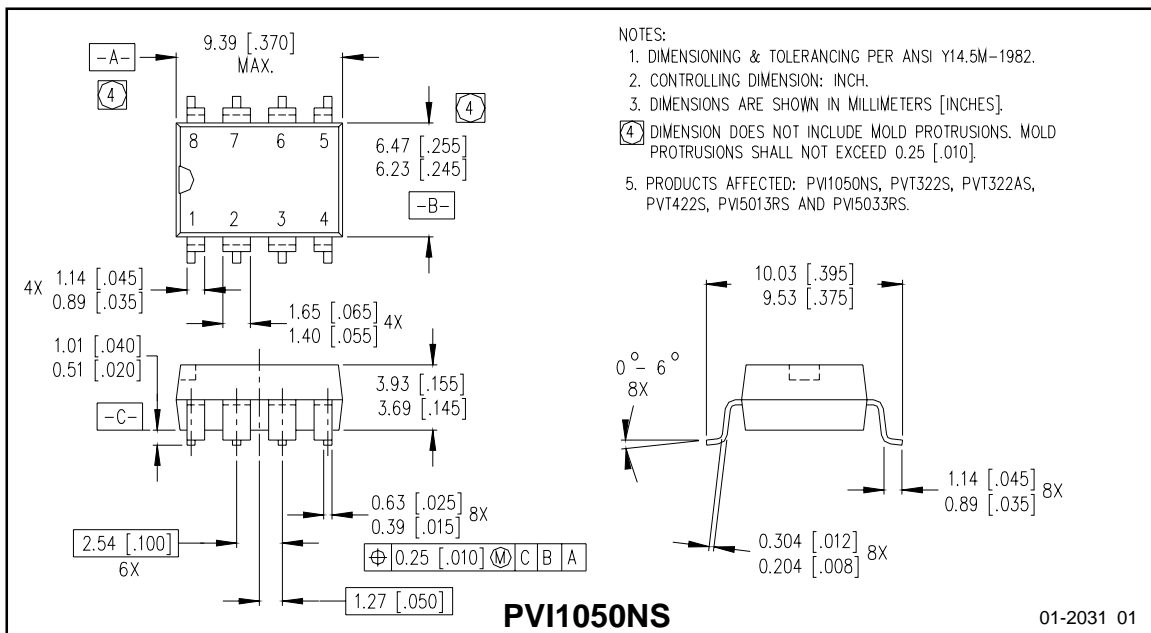
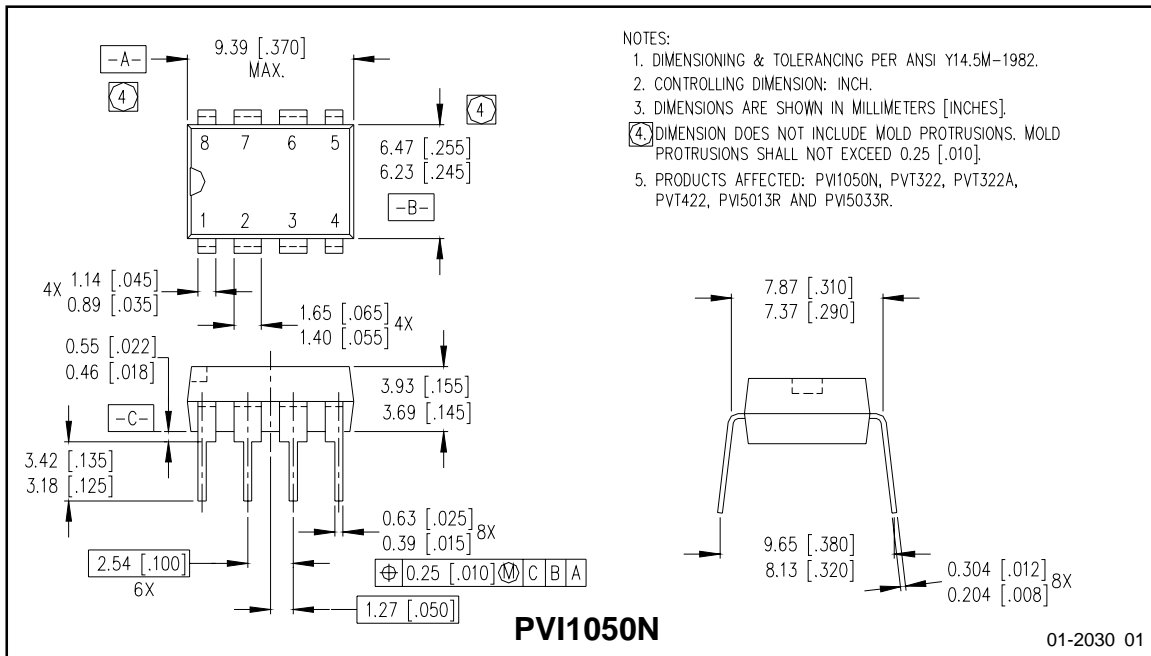
OUTPUT CHARACTERISTICS	PVI Series	Units
Maximum Forward Voltage @ 10μA	8.0 per channel	V _(DC)
Maximum Reverse Current @ -10VDC	10	μA(DC)

COUPLED CHARACTERISTICS	PVI5050N	PVI5080N	PVI1050N	Units
Minimum Open Circuit Voltage @ ILED = 10mA, 25°C, RL = >10MΩ (see figures 1 to 2)	5.0		5.0/channel 10 series	V (DC)
Minimum Short Circuit Current @ ILED = 10mA, 25°C (see figures 1 to 2)	5.0	8.0	5.0 /channel 10 parallel	μA (DC)
Maximum Capacitance (Input/Output)	1.0		2.0	pF
Maximum Ton Time @ ILED=10mA, CLOAD=10pF (See Figure7)	RL>20MΩ		300	μS
	RL=10MΩ		160	μS
	RL=4.7MΩ		90	μS
Maximum Toff Time @ ILED=10mA, CLOAD=10pF (See Figure7)	220			μS

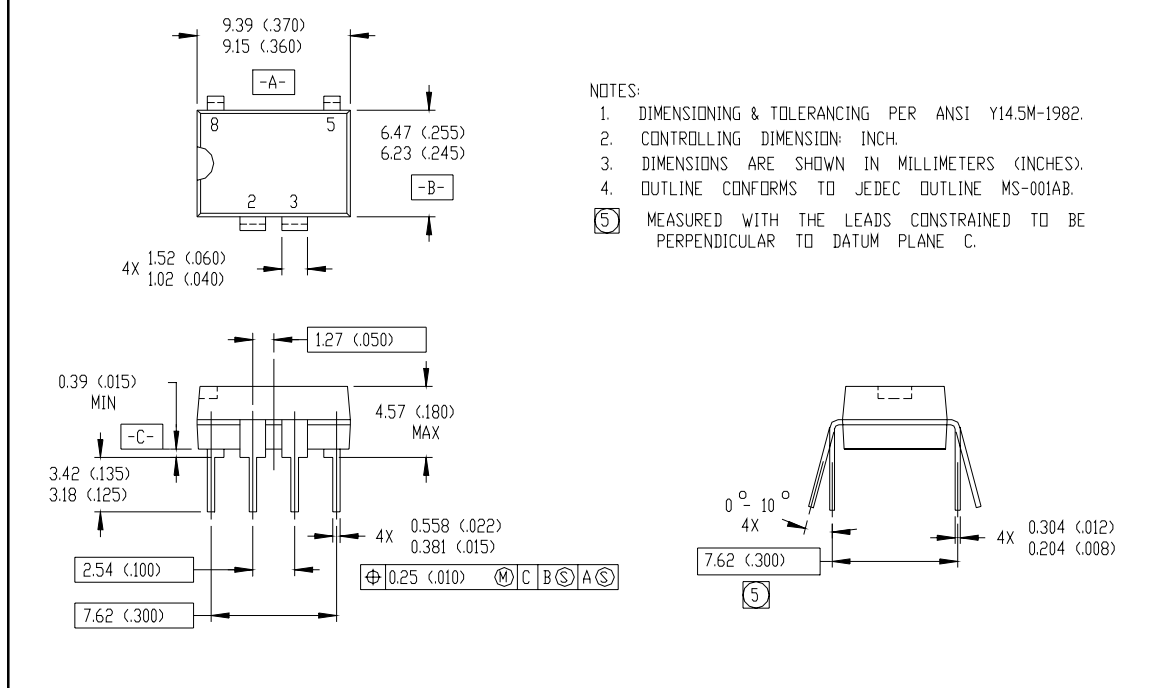
GENERAL CHARACTERISTICS	PVI5050N/5080N	PVI1050N	Units
Min. Dielectric Strength, Input-Output	4000	2500	V _{RMS}
Min. Dielectric Strength, Output-to-Output	1200		V _{DC}
Min. Insulation Resistance, Input-to-Output @ T _A =+25°C, 50%RH, 100V _{DC}	10 ¹²		Ω
Max. Pin Soldering Temperature (10 seconds max.)	+260		°C
Ambient Temperature Range: Operating	-40 to +85		°C
	Storage		-40 to +125

International Rectifier does not recommend the use of this product in aerospace, avionics, military or life support applications. Users of this International Rectifier product in such applications assume all risks of such use and indemnify International Rectifier against all damages resulting from such use.

Case Outlines

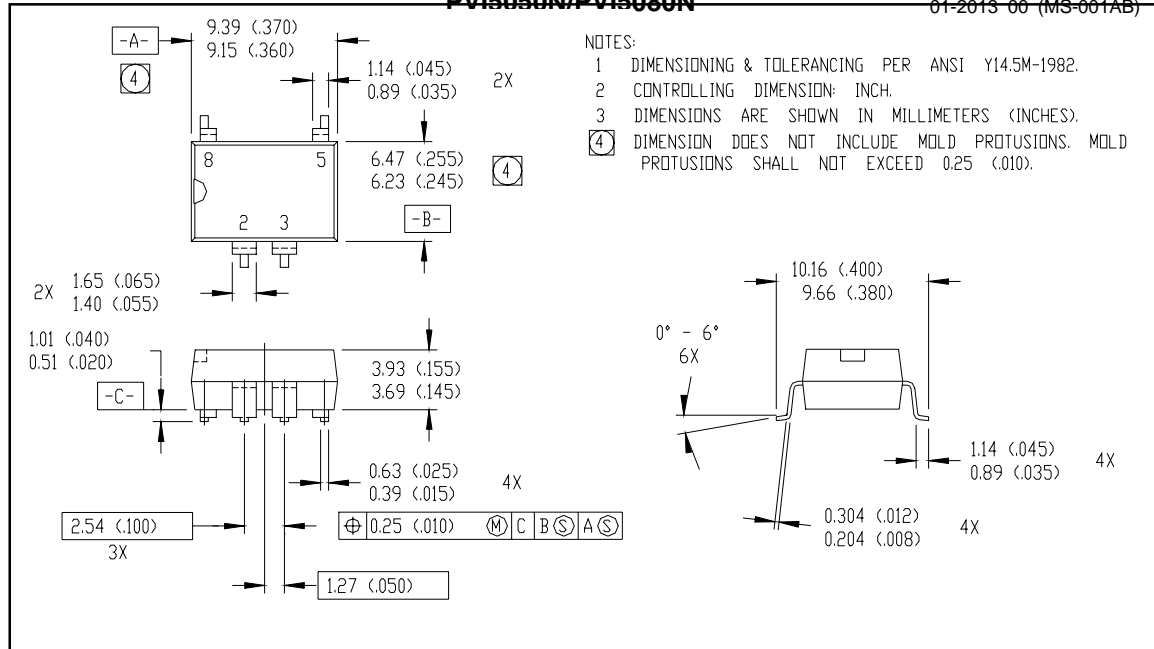


Case Outlines



PVI5050N/PVI5080N

01-2013 00 (MS-001AB)



PVI5050NS/PVI5080NS

01-2019 00